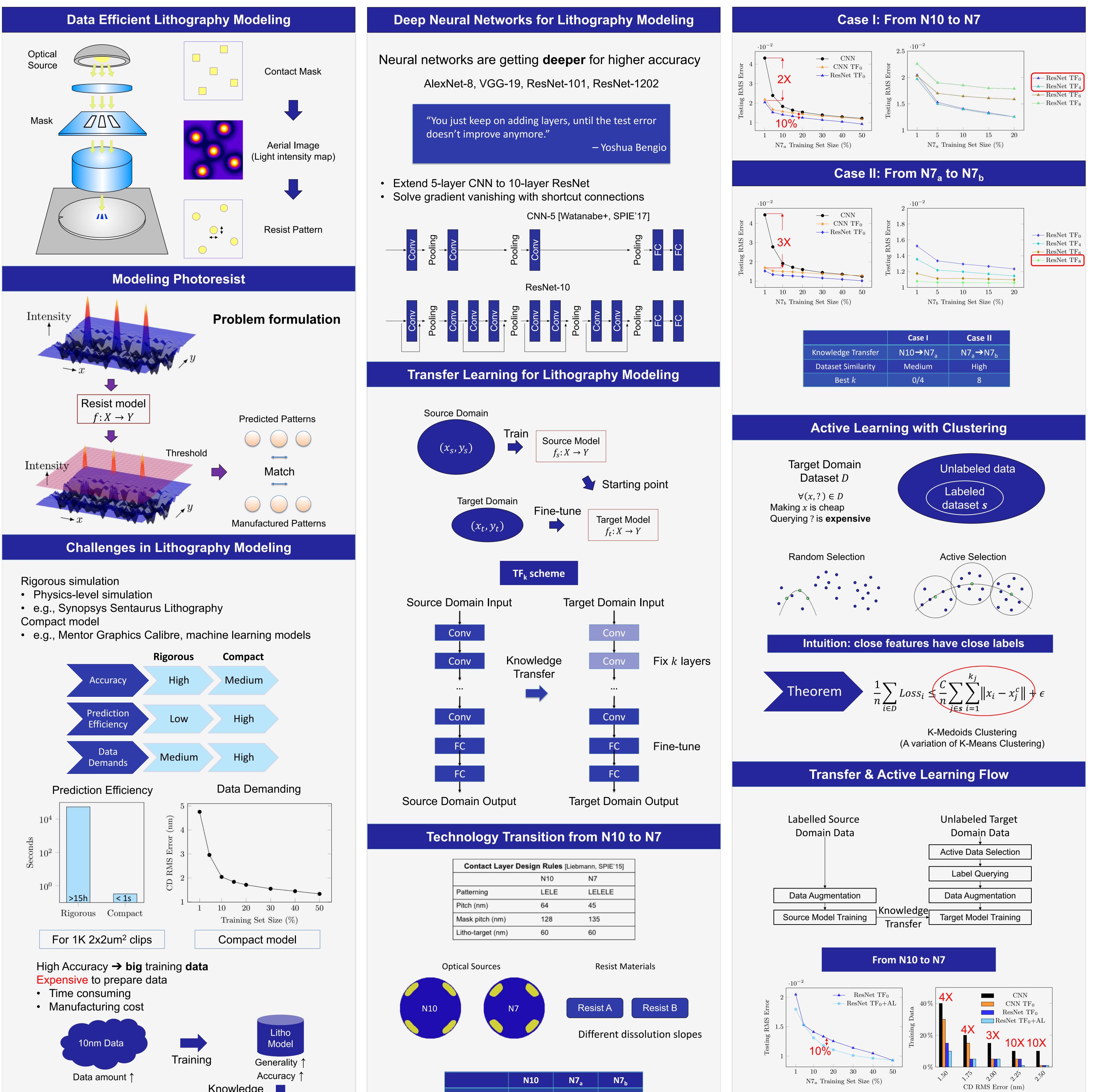
## **Data Efficient Lithography Modeling with Transfer Learning and Active Data Selection**

Yibo Lin<sup>1</sup>, Meng Li<sup>1</sup>, Yuki Watanabe<sup>2</sup>, Taiki Kimura<sup>2</sup>, Tetsuaki Matsunawa<sup>2</sup>, Shigeki Nojima<sup>2</sup>, David Z. Pan<sup>1</sup> <sup>1</sup>University of Texas at Austin, <sup>2</sup>Toshiba Memory Corporation

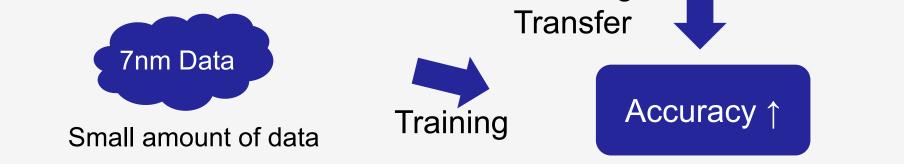


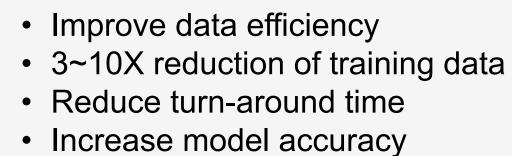
	Case I	Case II
Knowledge Transfer	N10→N7 <sub>a</sub>	N7 <sub>a</sub> →N7 <sub>b</sub>
Dataset Similarity	Medium	High
Best <i>k</i>	0/4	8



Contact Layer Design Rules [Liebmann, SPIE'15]				
	N10	N7		
Patterning	LELE	LELELE		
Pitch (nm)	64	45		
Mask pitch (nm)	128	135		
Litho-target (nm)	60	60		

	N10	N7 <sub>a</sub>	N7 <sub>b</sub>
Design Rule	А	В	В
Optical Source	А	В	В
Resist Material	A	A	В







http:/	/yibol	lin.com
--------	--------	---------

